3-to-8-line Decoder / Demultiplexer

HITACHI

ADE-205-068B(Z) Rev.2 September 1995

Description

The HD74LVC138 has three binary select inputs in a 16 pin package. If the device is enabled these inputs determine which one of the eight normally high outputs will go low. Two active low and one active high enables are provided to ease the cascading of decoders. Low voltage and high speed operation is suitable at the battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

Features

- $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V}$
- All inputs V_{IH} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V)
- Typical V_{OL} ground bounce < 0.8 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.0 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- High output current ± 24 mA (@V_{CC} = 3.0 V to 5.5 V)



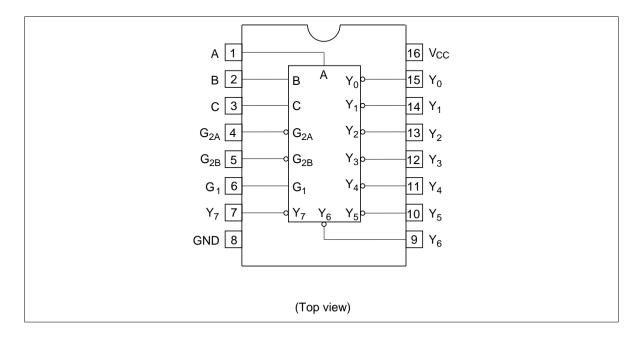
Function Table

Inputs

Enable Select			Outputs										
G ₁	$G_{\scriptscriptstyle 2A}$	G_{2B}	С	В	Α	Y ₀	Y ₁	Y ₂	Y_3	Y ₄	Y ₅	Y ₆	Y ₇
Χ	Χ	Н	Х	Χ	Х	Н	Н	Н	Н	Н	Н	Н	Н
Χ	Н	Х	Χ	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н
L	Χ	Х	Х	Χ	Х	Н	Н	Н	Н	Н	Н	Н	Н
Н	L	L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н
Н	L	L	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н
Н	L	L	L	Н	L	Н	Н	L	Н	Н	Н	Н	Н
Н	L	L	L	Н	Н	Н	Н	Н	L	Н	Н	Н	Н
Н	L	L	Н	L	L	Н	Н	Н	Н	L	Н	Н	Н
Н	L	L	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Н
Н	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	Н
Н	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L

H: High level
L: Low level
X: Immaterial

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V _{cc}	-0.5 to 6.0	V	
Input diode current	I _{IK}	- 50	mA	$V_1 = -0.5 \text{ V}$
Input voltage	Vı	-0.5 to 6.0	V	
Output diode current	I _{OK}	- 50	mA	$V_0 = -0.5 \text{ V}$
		50	mA	$V_0 = V_{CC} + 0.5 \text{ V}$
Output voltage	Vo	–0.5 to $V_{\rm CC}$ +0.5	V	
Output current	Io	±50	mA	
V _{cc} , GND current / pin	$I_{\rm CC}$ or $I_{\rm GND}$	100	mA	
Storage temperature	Tstg	-65 to +150	°C	

Note: The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V _{cc}	1.5 to 5.5	V	Data retention
		2.0 to 5.5	V	At operation
Input / output voltage	V_{I}	0 to 5.5	V	G, A, B, C
	V _o	0 to V _{cc}	V	Y ₀ to Y ₇
Operating temperature	Та	-40 to 85	°C	
Output current	I _{OH}	-12	mA	$V_{CC} = 2.7 \text{ V}$
		-24 ^{*2}	mA	V _{cc} = 3.0 V to 5.5 V
	I _{OL}	12	mA	$V_{CC} = 2.7 \text{ V}$
		24*2	mA	V _{cc} = 3.0 V to 5.5 V
Input rise / fall time *1	t _r , t _f	10	ns/V	

Notes: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

2. duty cycle $\leq 50\%$

Electrical Characteristics

Ta = -40 to 85°C

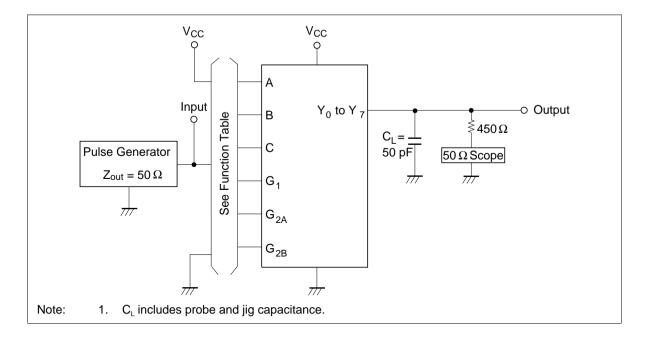
Item	Symbol	V _{cc} (V)	Min	Max	Unit	Test Conditions
Input voltage	V _{IH}	2.7 to 3.6	2.0	_	V	
		4.5 to 5.5	V _{CC} ×0.7	_	V	_
	V _{IL}	2.7 to 3.6	_	0.8	V	
		4.5 to 5.5	_	V _{cc} ×0.3	V	_
Output voltage	V_{OH}	2.7 to 5.5	V _{CC} -0.2	_	V	I _{OH} = -100 μA
		2.7	2.2	_	V	$I_{OH} = -12 \text{ mA}$
		3.0	2.4	_	V	_
		3.0	2.0	_	V	I _{OH} = -24 mA
		4.5	3.8	_	V	_
	V _{OL}	2.7 to 5.5	_	0.2	V	I _{OL} = 100 μA
		2.7	_	0.4	V	I _{OL} = 12 mA
		3.0	_	0.55	V	I _{OL} = 24 mA
		4.5	_	0.55	V	_
Input current	I _{IN}	0 to 5.5	_	±5.0	μΑ	V _{IN} = 5.5 V or GND
Quiescent supply current	I _{cc}	5.5	_	20	μΑ	V _{IN} = V _{CC} or GND
	ΔI_{CC}	3.0 to 3.6	_	500	μΑ	V_{IN} = one input at(V_{CC} –0.6)V, other inputs at V_{CC} or GND

Switching Characteristics

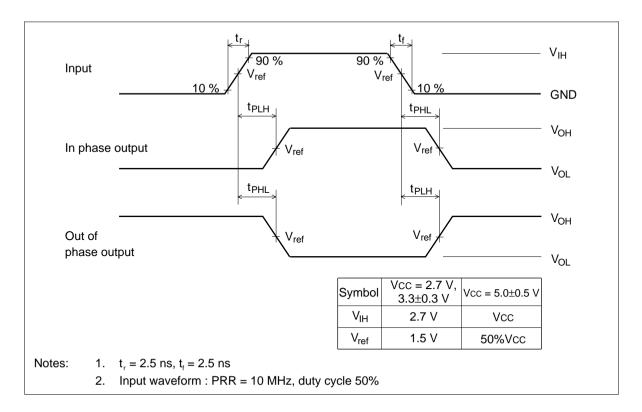
Ta = -40 to 85°C

Item	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	From (Input)	To (Output)
Propagation delay time	t _{PLH}	2.7	_	7.0	10.0	ns	G, A, B, C	Y ₀ to Y ₇
	$t_{\scriptscriptstylePHL}$	3.3±0.3	1.5	5.0	9.0	ns	_	
		5.0±0.5	_	3.5	7.5	ns	_	
Input capacitance	C _{IN}	2.7	_	3.0	_	pF		
Output capacitance	C _o	2.7	_	15.0	_	pF		

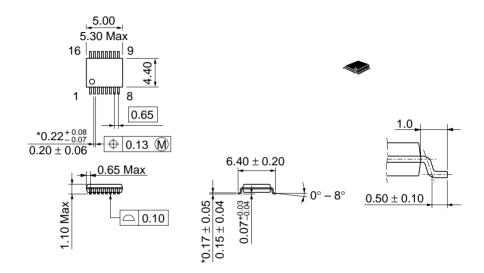
Test Circuit



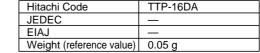
Waveforms



Unit: mm



*Dimension including the plating thickness
Base material dimension



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